

HB2010

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Studies of the effect of 2nd harmonic on the e-p instability and RF control of instabilities

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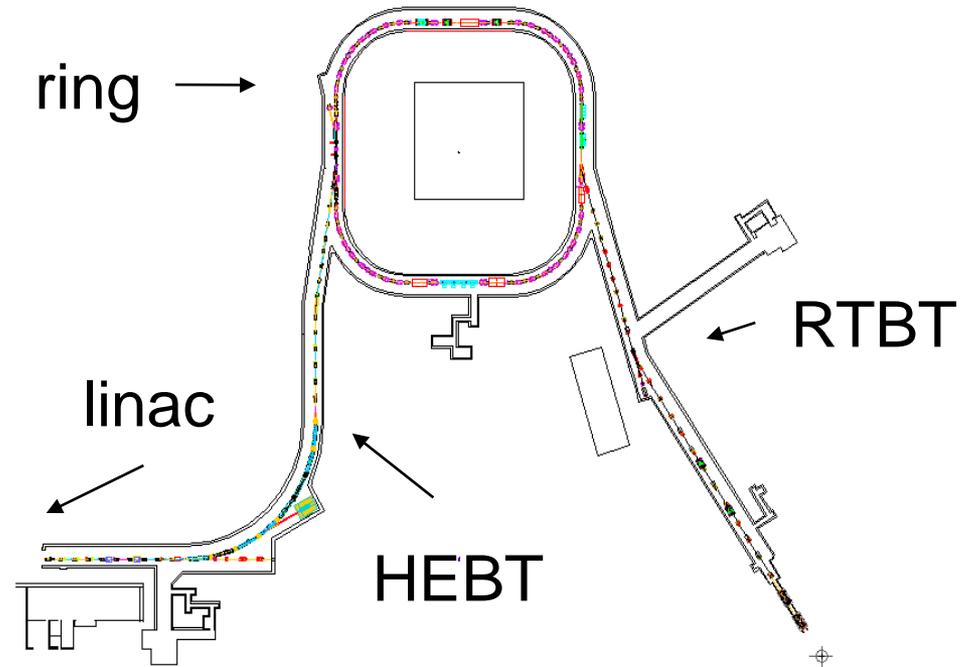
SNS/ORNL on behalf of SNS AP team

September 27– October 1, 2010

SNS Ring parameters

Ring parameters:

- ▽ ~ 1 GeV (860-931 MeV in our studies)
- 248 m perimeter
- ▽ ~ 10 cm VC radius
- Working point (6.23,6.21)
(5.795,5.81) – optional
- Design intensity – 1.4×10^{14} protons
- Power on target – 1.4 MW at first stage
- The ring design was low-loss high intensity oriented



Instability-related Features of Ring Design



Common high intensity design features:

high energy spread design and broadband
feedback provision +

For E-p instability mitigation:

a) Electron collection near stripper foil;

b) Experiments of 1999 showed significant reduction of electrons in a coated spool piece of PSR vacuum chamber. This led to a decision to coat all pieces of VC with TiN;

c) Solenoids near the regions with high loss;

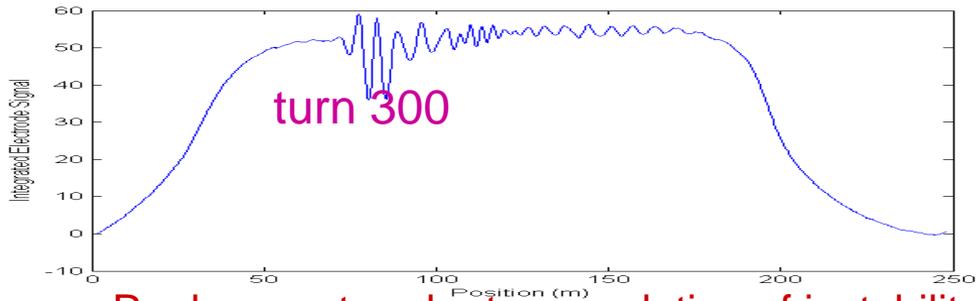
d) clearing electrode near the stripper foil;

e) Electron detectors for electron accumulation study.

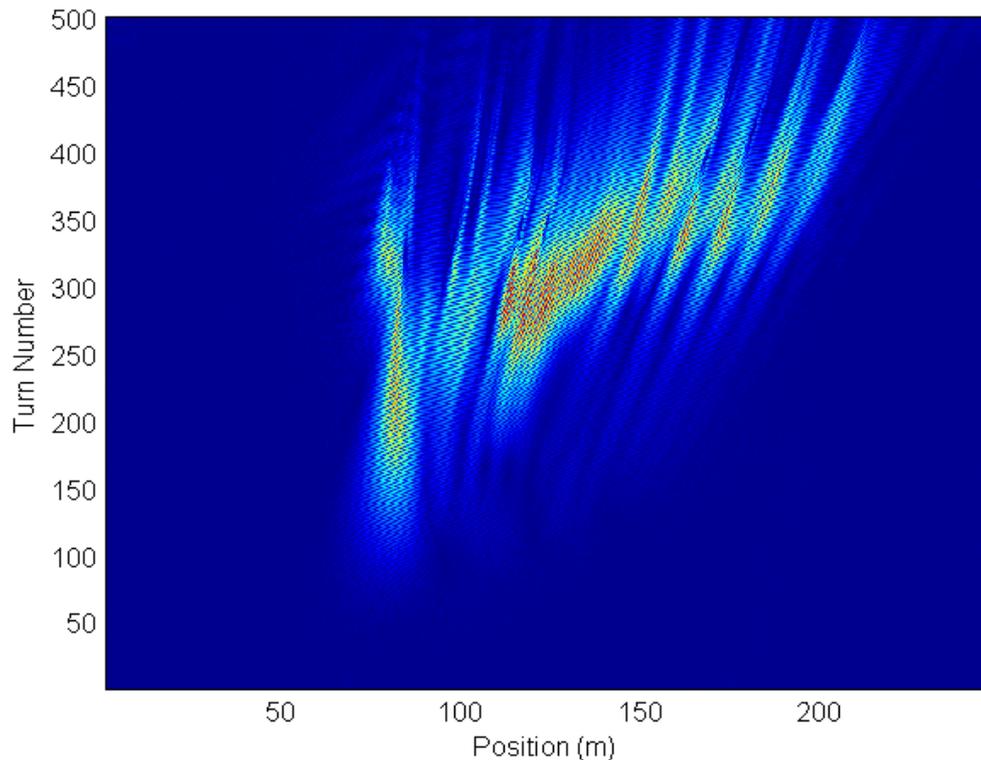
Also we have minimization of other impedances. We see extraction kicker and resistive wall instability, but they are much weaker than e-p instability

Some of the first observations of e-p instability

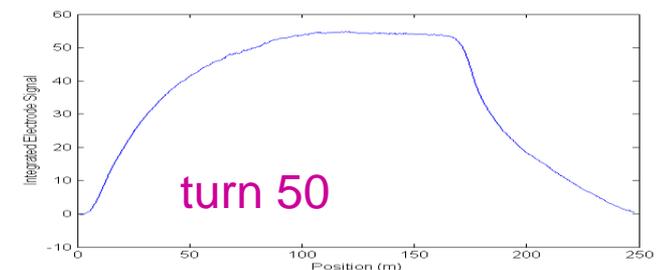
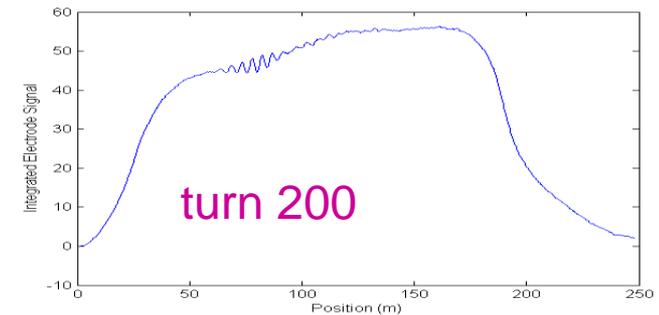
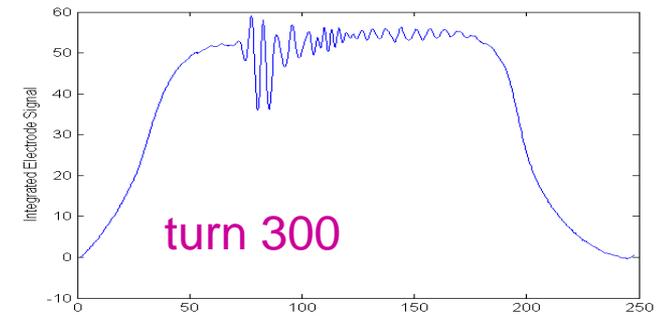
Instability occurs near flat top, closer to front of the beam, and moves backwards.



Real space turn-by-turn evolution of instability



Integrated signal for one electrode



Improvement of the threshold (2006-2010)



- 2006 – 10^{14} protons per pulse with instability
- 2007- 1.1×10^{14} protons per pulse with instability
- 2008- 1.3×10^{14} protons per pulse with instability
- 2009 – now – 1.1×10^{14} without instability and around 1.4×10^{14} with small instability

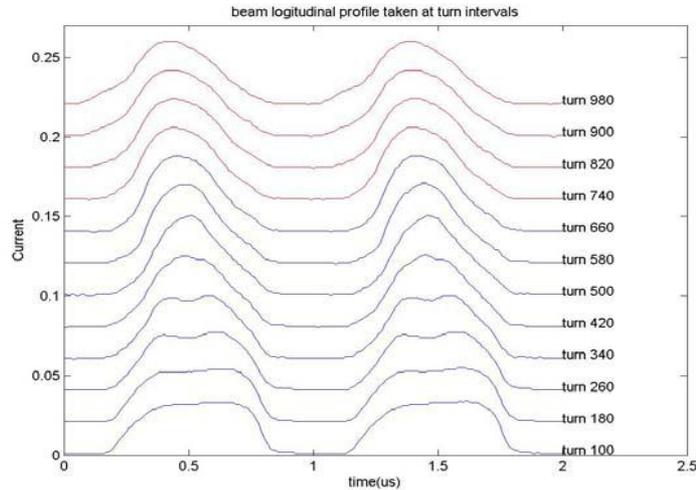
We attribute the improvements to low loss more “clean” beam in the ring

We noticed that manipulations with RF helped to eliminate instability

SNS RF has 3 1st harmonic cavities (around 1 MHz, 20 kV each) and 1 2nd harmonic cavity (2 MHz around 20 kV voltage)

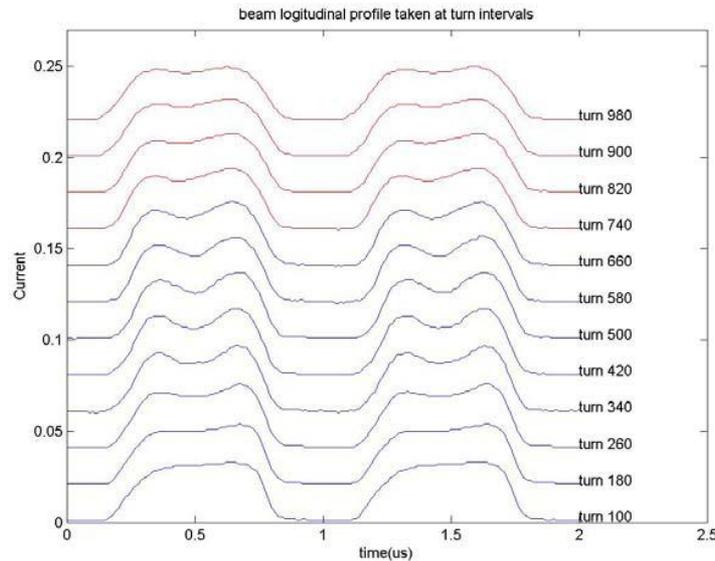
In our experiments we had 1 1st harmonic station off.

2009 experiments with RF manipulations



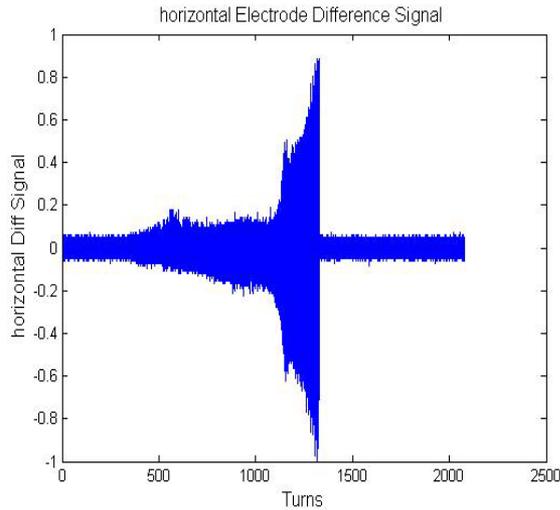
Intensity – $1.1 \cdot 10^{14}$ ppp
980 turns of accumulation

Upper plot – 1st harmonic RF
voltage 10 kV, 2nd V=15 kV
2nd harmonic phase = -5 deg

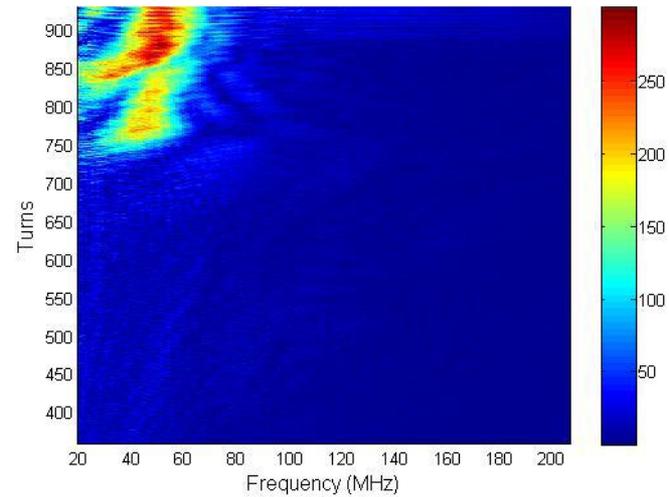


Lower plot - 1st harmonic RF
Voltage 5.5 kV, 2nd V=15 kV
2nd harmonic phase = -15 deg

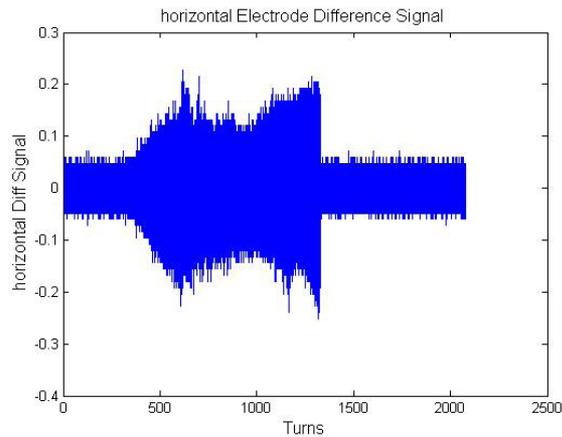
E-p instability signatures for these cases



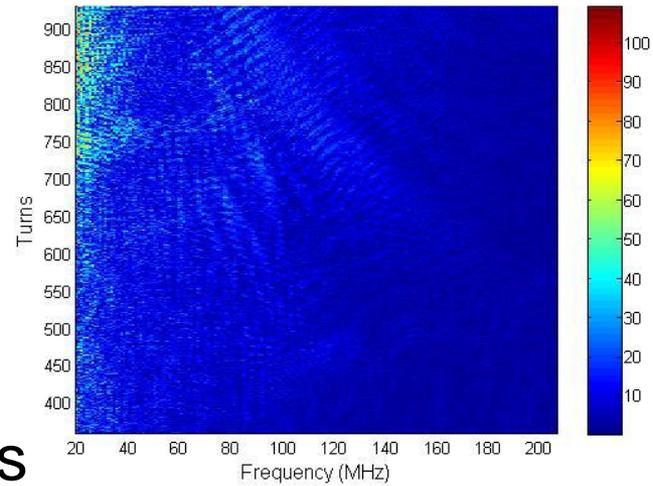
1st



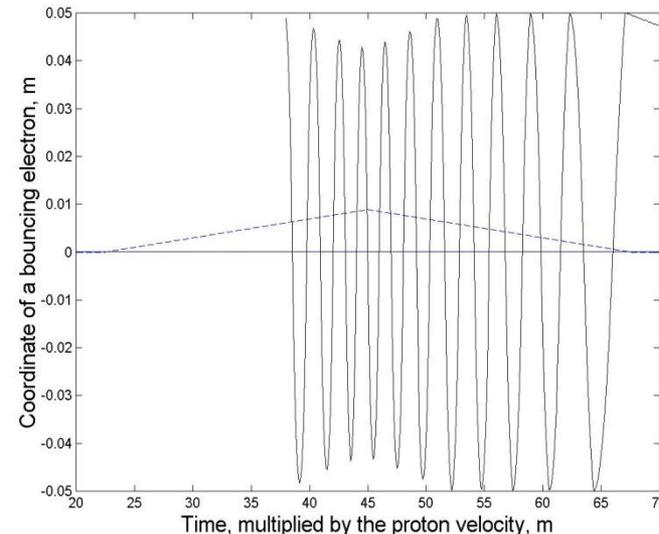
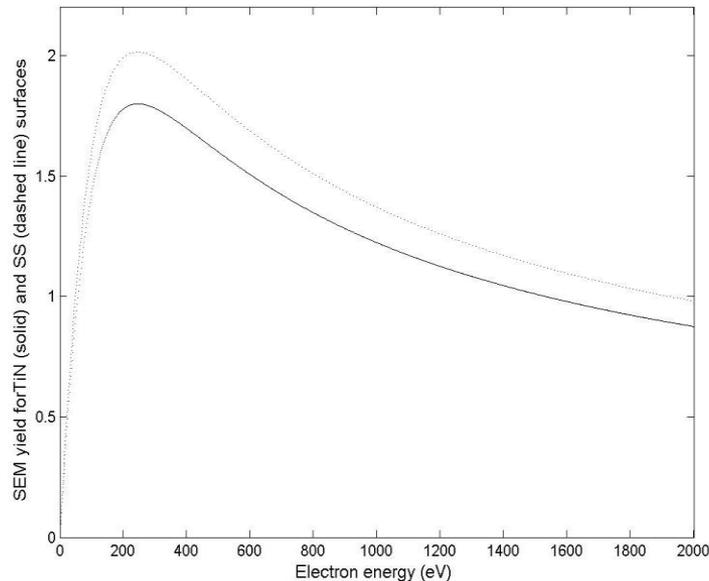
and



2nd
cases



Possible explanations of the phenomenon

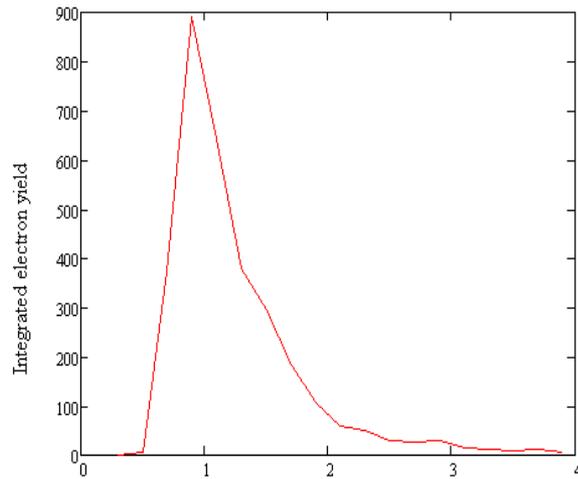


Pivi-Furman model
for SEM yield : SS
and TiN surfaces

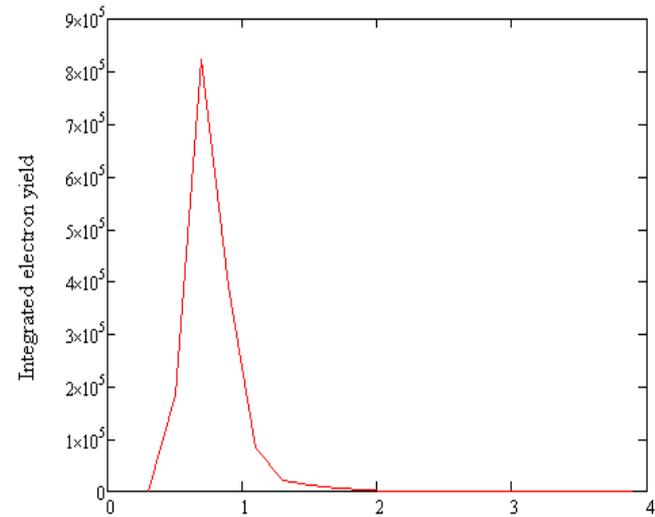
Electron motion in
a proton bunch field

SNS case – electrons have energy from 50 to 300 eV
when striking the vacuum chamber at the trailing edge

Possible explanations (cont.)



Relative duration of the trailing edge



Relative duration of the trailing edge

Integrated yield as a function of trailing edge steepness $s=200\text{ns}/(\text{trailing edge duration})$

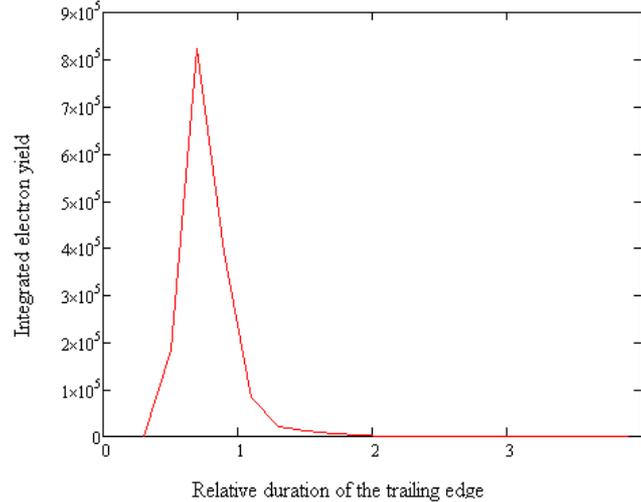
Left – SS chamber

Right- aluminum chamber

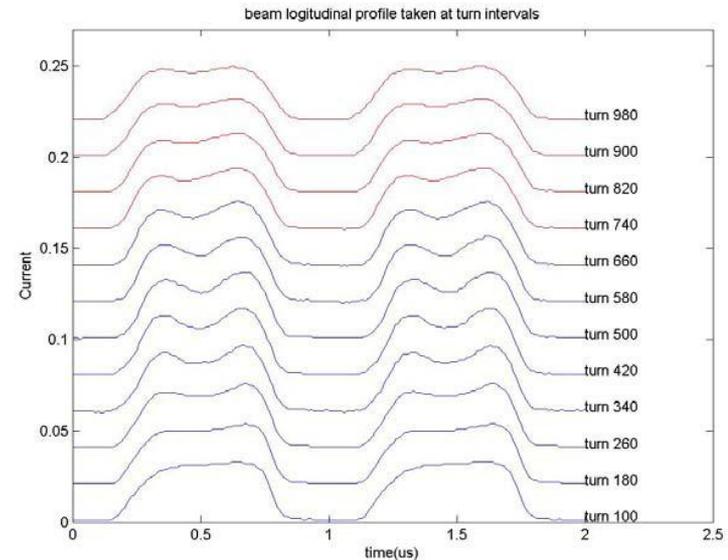
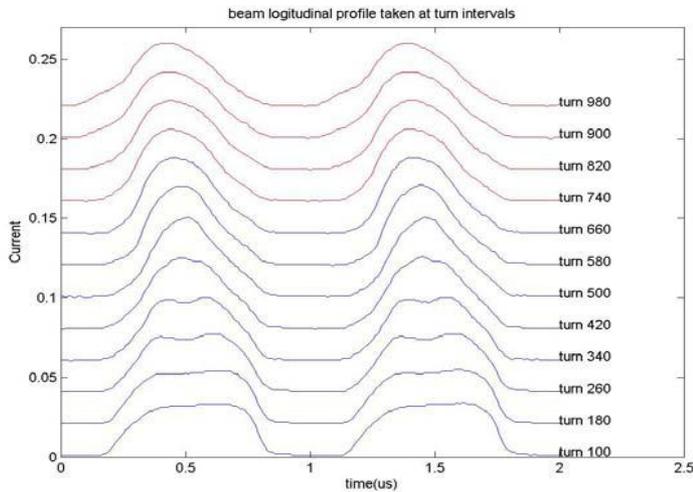
Possible explanations (cont.)

Integrated yield for aluminum

$s=0.7$

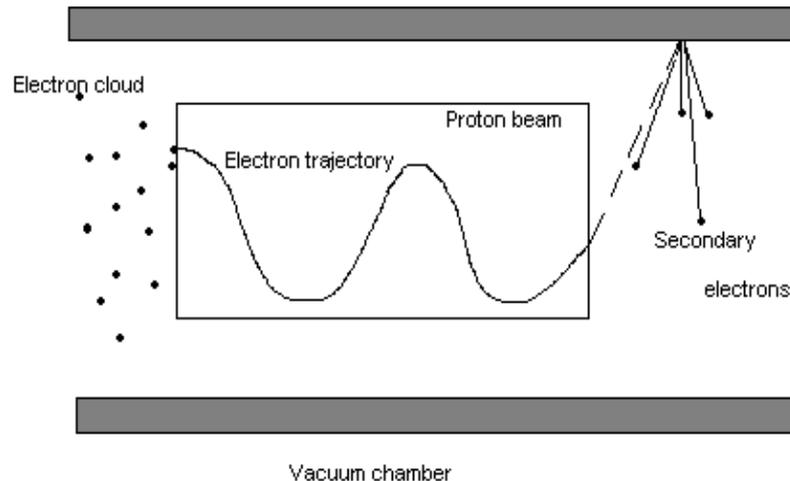


$s=1.4$



Optimal longitudinal distributions

- 1) Long trailing edge. Its drawback – the minimal parameter s can be around 0.5 only (sharp leading edge and the whole bunch is just trailing edge);
- 2) Short trailing edge. Parameter s can be in principle very high (high voltage barrier cavity) –it kills both trailing edge and in-gap electrons.



Conclusion



- SNS e-p instability experiments showed strong dependence of instability signals on RF configuration;
- Possible explanation – electron accumulation dependence on longitudinal distribution of the proton bunch;
- Two opposite cases (with long and short trailing edges) are identified to be the best for mitigating e-p instability
- The most promising case seems to be longitudinal distribution, created by high-voltage barrier cavity (this case is also very good for minimizing space charge effects, and even creating self-consistent space-charge distributions (SNS presentation in Tsukuba HB2006))